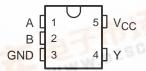
## 捷多邦,专业PCB打样工厂,24小时加**多N74**LVC1G132 SINGLE 2-INPUT NAND GATE

# WITH SCHMITT-TRIGGER INPUTS

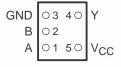
SCES546A - FEBRUARY 2004 - REVISED AUGUST 2004

- Available in Texas Instruments NanoStar™ and NanoFree™ Packages
- Supports 5-V V<sub>CC</sub> Operation
- Inputs Accept Voltages to 5.5 V
- Max t<sub>pd</sub> of 5.3 ns at 3.3 V
- Low Power Consumption, 10-μA Max I<sub>CC</sub>
- ±24-mA Output Drive at 3.3 V
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

# DBV OR DCK PACKAGE (TOP VIEW)



# YEP OR YZP PACKAGE (BOTTOM VIEW)



## description/ordering information

The SN74LVC1G132 contains one 2-input NAND gate with Schmitt-trigger inputs designed for 1.65-V to 5.5-V  $V_{CC}$  operation and performs the Boolean function  $Y = \overline{A} \bullet \overline{B}$  or  $Y = \overline{A} + \overline{B}$  in positive logic.

Because of Schmitt action, this device has different input threshold levels for positive-going  $(V_{T+})$  and negative-going  $(V_{T-})$  signals.

This device can be triggered from the slowest of input ramps and still give clean jitter-free output signals.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

NanoStar<sup>™</sup> and NanoFree<sup>™</sup> package technology is a major breakthrough in IC packaging concepts, using the die as the package.

#### **ORDERING INFORMATION**

TA	PACKAGET	ORDERABLE PART NUMBER	TOP-SIDE MARKING‡		
NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YEP		D I . ( 0000	SN74LVC1G132YEPR	DE	
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74LVC1G132YZPR	D5_	
-40°C to 85°C	207 (207 22)	Reel of 3000	SN74LVC1G132DBVR	000	
	SOT (SOT-23) – DBV	Reel of 250	SN74LVC1G132DBVT	C3B_	
	00T (00 70) DOV	Reel of 3000	SN74LVC1G132DCKR	D.F.	
	SOT (SC-70) – DCK	Reel of 250	SN74LVC1G132DCKT	D5_	

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





<sup>&</sup>lt;sup>‡</sup> DBV/DCK: The actual top-side marking has one additional character that designates the assembly/test site.

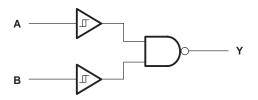
YEP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, ● = Pb-free).

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#### **FUNCTION TABLE**

INP	UTS	OUTPUT
Α	В	Υ
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

## logic diagram (positive logic)



## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>	
Voltage range applied to any output in the high-impedance or power-off state, VO	
(see Note 1)	–0.5 V to 6.5 V
Voltage range applied to any output in the high or low state, VO	
(see Notes 1 and 2)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)	–50 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	
Continuous output current, I <sub>O</sub>	
Continuous current through V <sub>CC</sub> or GND	±100 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 3): DBV package	206°C/W
DCK package	252°C/W
YEP/YZP package	132°C/W
Storage temperature range, T <sub>stq</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
  - 2. The value of V<sub>CC</sub> is provided in the recommended operating conditions table.
  - 3. The package thermal impedance is calculated in accordance with JESD 51-7.



# **SN74LVC1G132** SINGLE 2-INPUT NAND GATE WITH SCHMITT-TRIGGER INPUTS SCES546A - FEBRUARY 2004 - REVISED AUGUST 2004

## recommended operating conditions (see Note 4)

			MIN	MAX	UNIT
.,	Ownerhouselforms	Operating	1.65	5.5	
VCC	Supply voltage	Data retention only	1.5		V
٧ <sub>I</sub>	Input voltage		0	5.5	V
٧o	Output voltage		0	VCC	V
		V <sub>CC</sub> = 1.65 V		-4	
	OH High-level output current	V <sub>CC</sub> = 2.3 V		-8	
loh		у оу		-16	mA
		VCC = 3 V		-24	
		V <sub>CC</sub> = 4.5 V		-32	
		V <sub>CC</sub> = 1.65 V		4	
		V <sub>CC</sub> = 2.3 V		8	
loL	Low-level output current	у оу		16	mA
		VCC = 3 V		24	
		V <sub>CC</sub> = 4.5 V			
TA	Operating free-air temperature		-40	85	°C

NOTE 4: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

## **SN74LVC1G132 SINGLE 2-INPUT NAND GATE** WITH SCHMITT-TRIGGER INPUTS SCES546A - FEBRUARY 2004 - REVISED AUGUST 2004

## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	VCC	MIN	TYPT MAX	UNIT	
		1.65 V	0.79	1.16		
l		2.3 V	1.11	1.56		
V <sub>T+</sub> Positive-going input threshold voltage		3 V	1.5	1.87	V	
Toolave going input anoshold voltage		4.5 V	2.16	2.74		
		5.5 V	2.61	3.33		
		1.65 V	0.39	0.62		
,,		2.3 V	0.58	0.87		
V <sub>T</sub> _ Negative-going input threshold voltage		3 V	0.84	1.14	V	
Tregative going input timeshold voltage		4.5 V	1.41	1.79		
		5.5 V	1.87	2.29		
		1.65 V	0.37	0.62		
ΔVT		2.3 V	0.48	0.77		
Hysteresis		3 V	0.56	0.87	V	
$(V_{T+} - V_{T-})$		4.5 V	0.71	1.04		
		5.5 V	0.71	1.11		
	I <sub>OH</sub> = -100 μA	1.65 V to 5.5 V	V <sub>CC</sub> - 0.1			
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2			
	I <sub>OH</sub> = -8 mA	2.3 V	1.9			
VOH	$I_{OH} = -16 \text{ mA}$		2.4		V	
	I <sub>OH</sub> = -24 mA	3 V	2.3			
	I <sub>OH</sub> = -32 mA	4.5 V	3.8			
	I <sub>OL</sub> = 100 μA	1.65 V to 5.5 V		0.1		
	I <sub>OL</sub> = 4 mA	1.65 V		0.45		
W- :	I <sub>OL</sub> = 8 mA	2.3 V		0.3	V	
V <sub>OL</sub>	I <sub>OL</sub> = 16 mA	3 V		0.4	V	
	I <sub>OL</sub> = 24 mA	3 V		0.55		
_	I <sub>OL</sub> = 32 mA	4.5 V		0.55		
I <sub>I</sub> A or B inputs	$V_I = 5.5 \text{ V or GND}$	1.65 V to 5.5 V		±1	μΑ	
l <sub>off</sub>	$V_I$ or $V_O = 5.5 V$	0		±10	μΑ	
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	1.65 V to 5.5 V		10	μΑ	
Δl <sub>CC</sub>	One input at V <sub>CC</sub> – 0.6 V, Other inputs at V <sub>CC</sub> or GND	3 V to 5.5 V		500	μА	
Ci	V <sub>I</sub> = V <sub>CC</sub> or GND	3.3 V		3.5	pF	

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C.

# switching characteristics over recommended operating free-air temperature range, $C_L$ = 15 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = ± 0.1		V <sub>CC</sub> =		V <sub>CC</sub> =		V <sub>CC</sub> =		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
<sup>t</sup> pd	A or B	Y	4	16	2.5	7	2	5.3	1.5	4.4	ns



## **SN74LVC1G132 SINGLE 2-INPUT NAND GATE** WITH SCHMITT-TRIGGER INPUTS SCES546A - FEBRUARY 2004 - REVISED AUGUST 2004

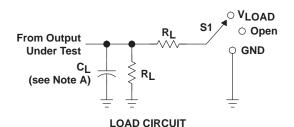
switching characteristics over recommended operating free-air temperature range,  $C_L$  = 30 pF or 50 pF (unless otherwise noted) (see Figure 2)

PARAMETER	FROM TO		V <sub>CC</sub> = 1.8 V ± 0.15 V			V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 5 V ± 0.5 V		UNIT	
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	A or B	Υ	4	16	3	7.5	2	6	2	5	ns

## operating characteristics, $T_A = 25^{\circ}C$

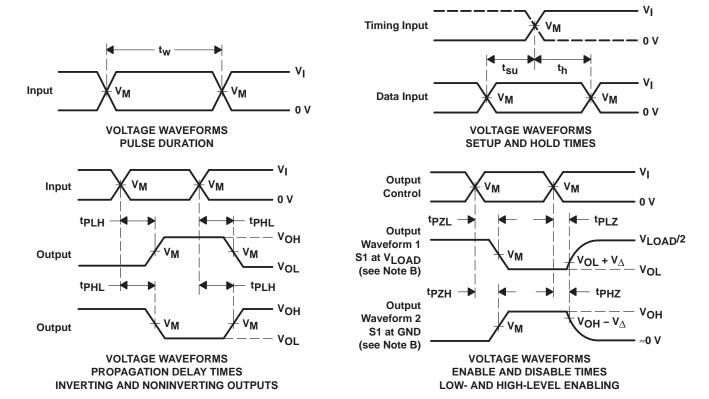
PARAMETER		TEST	V <sub>CC</sub> = 1.8 V	$V_{CC} = 2.5 \text{ V}$	$V_{CC} = 3.3 \text{ V}$	$V_{CC} = 5 V$	LINUT	
	FARAMETER	CONDITIONS	TYP	TYP TYP		TYP	UNIT	
C <sub>pd</sub>	Power dissipation capacitance	f = 10 MHz	17	18	18	20	pF	

#### PARAMETER MEASUREMENT INFORMATION



TEST	S1
tPLH/tPHL	Open
tPLZ/tPZL	VLOAD
tPHZ/tPZH	GND

.,	INF	PUTS	.,	v	•	_	.,
VCC	٧ <sub>I</sub>	t <sub>r</sub> /t <sub>f</sub>	VM	VLOAD	CL	RL	$v_{\scriptscriptstyle\Delta}$
1.8 V $\pm$ 0.15 V	VCC	≤2 ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	15 pF	<b>1 M</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	VCC	≤2 ns	V <sub>CC</sub> /2	2×VCC	15 pF	<b>1 Μ</b> Ω	0.15 V
3.3 V $\pm$ 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	15 pF	<b>1 Μ</b> Ω	0.3 V
5 V $\pm$ 0.5 V	VCC	≤2.5 ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	15 pF	<b>1 M</b> Ω	0.3 V

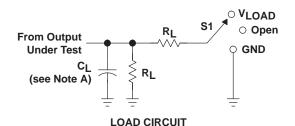


- NOTES: A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ .
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E. tpLZ and tpHZ are the same as tdis.
  - F. tpzL and tpzH are the same as ten.
  - G. tpLH and tpHL are the same as tpd.
  - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

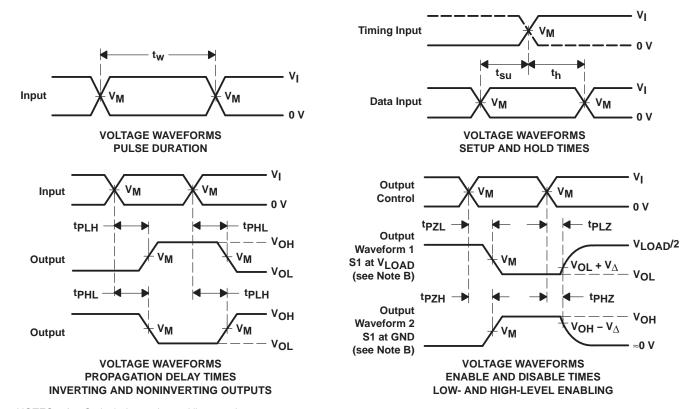


#### PARAMETER MEASUREMENT INFORMATION



TEST	S1
tPLH/tPHL	Open
tPLZ/tPZL	VLOAD
tPHZ/tPZH	GND

.,	INF	PUTS		V		_	.,
VCC	٧ <sub>I</sub>	t <sub>r</sub> /t <sub>f</sub>	VM	VLOAD	CL	RL	$v_{\scriptscriptstyle\Delta}$
1.8 V $\pm$ 0.15 V	VCC	≤ <b>2</b> ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	30 pF	<b>1 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	VCC	≤2 ns	V <sub>CC</sub> /2	2×VCC	30 pF	<b>500</b> Ω	0.15 V
3.3 V $\pm$ 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5 V $\pm$ 0.5 V	VCC	≤2.5 ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	50 pF	500 Ω	0.3 V



NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O$  = 50  $\Omega$
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.
- H. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms





### PACKAGE OPTION ADDENDUM

18-Mar-2005

#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN74LVC1G132DBVR	ACTIVE	SOT-23	DBV	5	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G132DBVT	ACTIVE	SOT-23	DBV	5	250	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G132DCKR	ACTIVE	SC70	DCK	5	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G132DCKT	ACTIVE	SC70	DCK	5	250	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G132YEPR	ACTIVE	WCSP	YEP	5	3000	TBD	SNPB	Level-1-260C-UNLIM
SN74LVC1G132YZPR	ACTIVE	WCSP	YZP	5	3000	Pb-Free (RoHS)	SNAGCU	Level-1-260C-UNLIM

<sup>&</sup>lt;sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

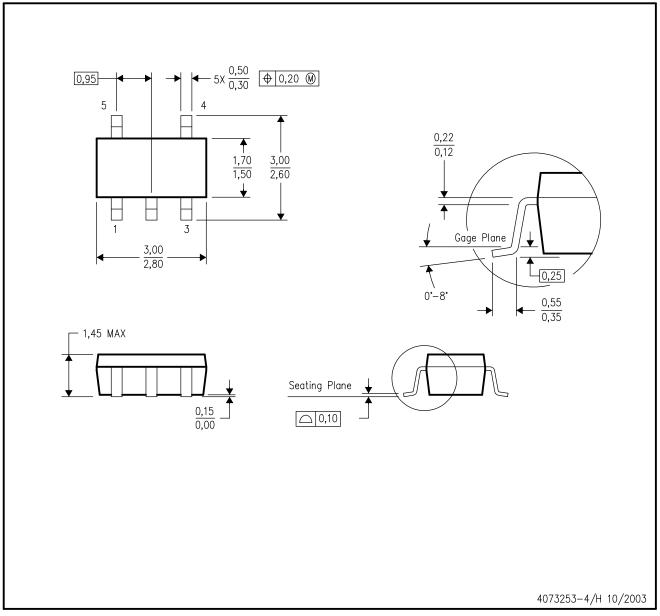
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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# DBV (R-PDSO-G5)

## PLASTIC SMALL-OUTLINE PACKAGE



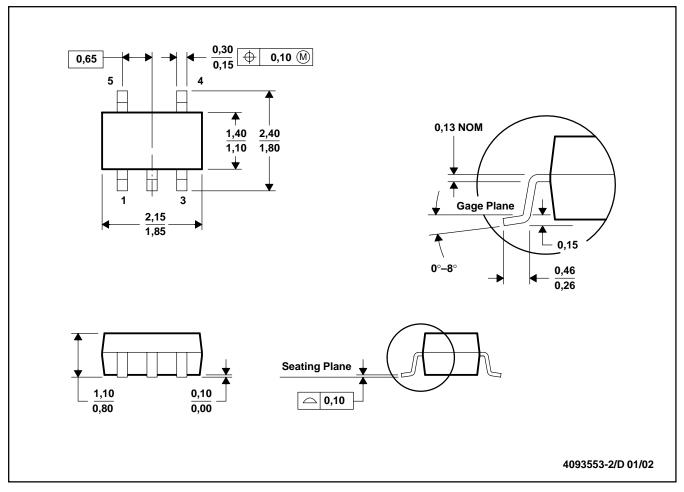
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-178 Variation AA.



## DCK (R-PDSO-G5)

#### PLASTIC SMALL-OUTLINE PACKAGE

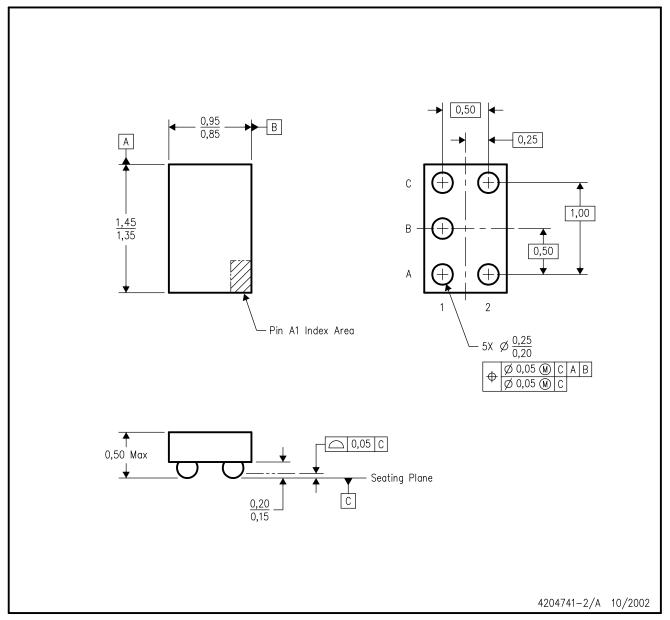


NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-203

# YZP (R-XBGA-N5)

## DIE-SIZE BALL GRID ARRAY



NOTES:

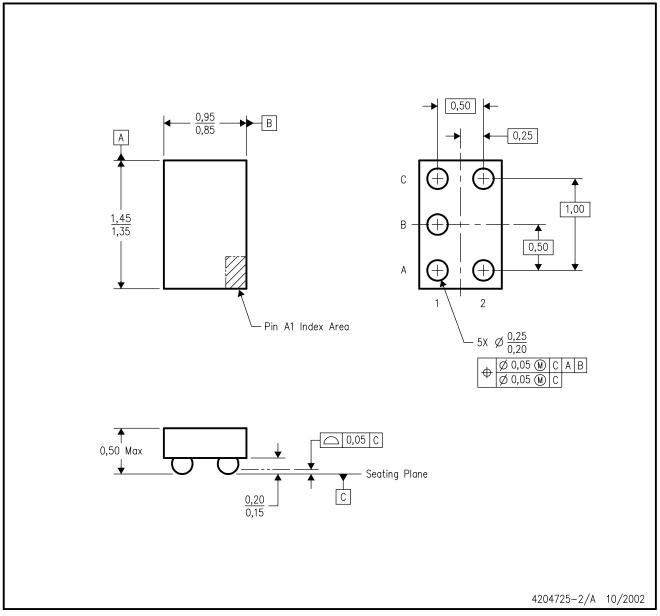
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This package is lead-free. Refer to the 5 YEP package (drawing 4204725) for tin-lead (SnPb).

NanoFree is a trademark of Texas Instruments.



# YEP (R-XBGA-N5)

## DIE-SIZE BALL GRID ARRAY



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. NanoStar™ package configuration.
- D. This package is tin-lead (SnPb). Refer to the 5 YZP package (drawing 4204741) for lead-free.

NanoStar is a trademark of Texas Instruments.



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